

# 9N90-FC

**Power MOSFET**

## 9.0A, 900V N-CHANNEL POWER MOSFET

### ■ DESCRIPTION

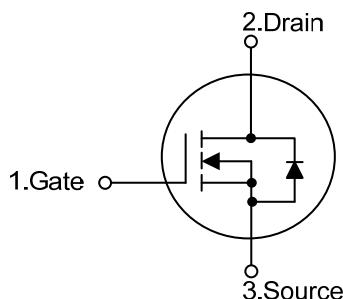
The UTC **9N90-FC** is a N-channel enhancement MOSFET using UTC's advanced technology to provide the customers with perfect  $R_{DS(ON)}$ , high switching speed, high current capacity and low gate charge.

The UTC **9N90-FC** is universally applied in low voltage such as automotive, high efficiency switching for AC/DC converters and DC motor control, etc.

### ■ FEATURES

- \*  $R_{DS(ON)} \leq 1.4 \Omega$  @  $V_{GS}=10V$ ,  $I_D=4.5A$
- \* Low Reverse Transfer Capacitance
- \* Fast Switching Capability
- \* Avalanche Energy Specified
- \* Improved dv/dt Capability, High Ruggedness

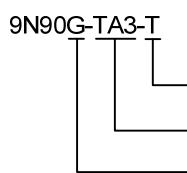
### ■ SYMBOL



### ■ ORDERING INFORMATION

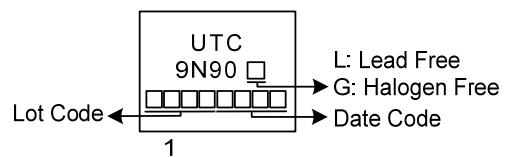
Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
9N90L-TA3-T	9N90G-TA3-T	TO-220	G	D	S	Tube
9N90L-TF1-T	9N90G-TF1-T	TO-220F1	G	D	S	Tube
9N90L-TF2-T	9N90G-TF2-T	TO-220F2	G	D	S	Tube
9N90L-TF3-T	9N90G-TF3-T	TO-220F	G	D	S	Tube
9N90L-T47-T	9N90G-T47-T	TO-247	G	D	S	Tube
9N90L-T3P-T	9N90G-T3P-T	TO-3P	G	D	S	Tube

Note: Pin Assignment: G: Gate D: Drain S: Source



(1) T: Tube  
 (2) TA3: TO-220, TF1: TO-220F1, TF2: TO-220F2  
 TF3: TO-220F, T3P: TO-3P, T47: TO-247  
 (3) G: Halogen Free and Lead Free, L: Lead Free

## ■ MARKING



■ ABSOLUTE MAXIMUM RATINGS ( $T_c=25^\circ\text{C}$ , unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		$V_{DSS}$	900	V
Gate-Source Voltage		$V_{GSS}$	$\pm 30$	V
Drain Current	Continuous	$I_D$	9	A
	Pulsed (Note 2)	$I_{DM}$	18	A
Avalanche Energy	Single Pulsed (Note 3)	$E_{AS}$	375	mJ
Peak Diode Recovery $dv/dt$ (Note 4)		$dv/dt$	2	V/ns
Power Dissipation	TO-220	$P_D$	130	W
	TO-220F/TO-220F1		36	W
	TO-220F2		220	W
	TO-247		230	W
	TO-3P		+150	°C
Junction Temperature		$T_J$	-55 ~ +150	°C
Storage Temperature		$T_{STG}$		

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. Repetitive Rating : Pulse width limited by maximum junction temperature.

3.  $L=30\text{mH}$ ,  $I_{AS}=5.0\text{A}$ ,  $V_{DD}=50\text{V}$ ,  $R_G=25\Omega$ , Starting  $T_J = 25^\circ\text{C}$

4.  $I_{SD} \leq 9.0\text{A}$ ,  $di/dt \leq 200\text{A}/\mu\text{s}$ ,  $V_{DD} \leq BV_{DSS}$ , Starting  $T_J = 25^\circ\text{C}$

■ THERMAL DATA

PARAMETER		SYMBOL	RATINGS	UNIT
Junction to Ambient	TO-220/TO-220F	$\theta_{JA}$	62.5	°C/W
	TO-220F1/TO-220F2		50	°C/W
	TO-247		40	°C/W
	TO-3P		0.96	°C/W
Junction to Case	TO-220	$\theta_{JC}$	3.4	°C/W
	TO-220F/TO-220F1		0.57	°C/W
	TO-220F2		0.54	°C/W
	TO-247			
	TO-3P			

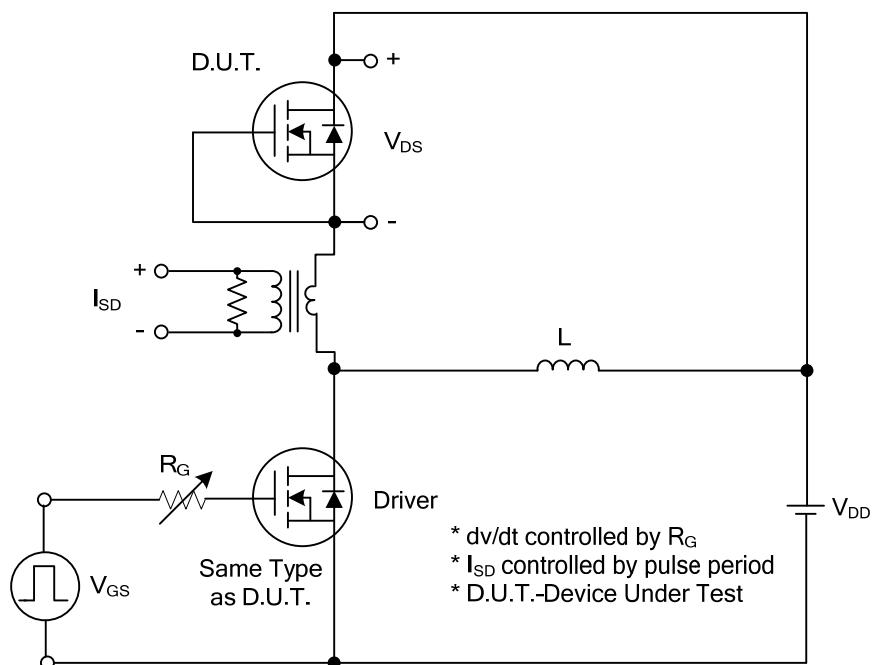
■ ELECTRICAL CHARACTERISTICS ( $T_J = 25^\circ\text{C}$ , unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>OFF CHARACTERISTICS</b>						
Drain-Source Breakdown Voltage	$\text{BV}_{\text{DSS}}$	$V_{\text{GS}}=0\text{V}, I_{\text{D}}=250\mu\text{A}$	900			V
Drain-Source Leakage Current	$I_{\text{DSS}}$	$V_{\text{DS}}=900\text{V}, V_{\text{GS}}=0\text{V}$		10		$\mu\text{A}$
Gate-Source Leakage Current	$I_{\text{GSS}}$	$V_{\text{GS}}=\pm 30\text{V}, V_{\text{DS}}=0\text{V}$			$\pm 100$	nA
<b>ON CHARACTERISTICS</b>						
Gate Threshold Voltage	$V_{\text{GS}(\text{TH})}$	$V_{\text{DS}}=V_{\text{GS}}, I_{\text{D}}=250\mu\text{A}$	3.0		5.0	V
Static Drain-Source On-State Resistance	$R_{\text{DS}(\text{ON})}$	$V_{\text{GS}}=10\text{V}, I_{\text{D}}=4.5\text{A}$			1.4	$\Omega$
<b>DYNAMIC CHARACTERISTICS</b>						
Input Capacitance	$C_{\text{ISS}}$	$V_{\text{DS}}=25\text{V}, V_{\text{GS}}=0\text{V}, f=1\text{MHz}$		1800		pF
Output Capacitance	$C_{\text{OSS}}$			160		pF
Reverse Transfer Capacitance	$C_{\text{RSS}}$			2.2		pF
<b>SWITCHING CHARACTERISTICS</b>						
Total Gate Charge (Note 1)	$Q_G$	$V_{\text{DS}}=720\text{V}, V_{\text{GS}}=10\text{V}, I_{\text{D}}=9.0\text{A}$ $I_G=1\text{mA}$ (Note 1, 2)		30		nC
Gate-Source Charge	$Q_{\text{GS}}$			10		nC
Gate-Drain Charge	$Q_{\text{GD}}$			4		nC
Turn-On Delay Time (Note 1)	$t_{\text{D}(\text{ON})}$	$V_{\text{DD}}=100\text{V}, V_{\text{GS}}=10\text{V}, I_{\text{D}}=9.0\text{A}, R_G=25\Omega$ (Note 1, 2)		24		ns
Turn-On Rise Time	$t_R$			18		ns
Turn-Off Delay Time	$t_{\text{D}(\text{OFF})}$			76		ns
Turn-Off Fall Time	$t_F$			40		ns
<b>SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS</b>						
Maximum Continuous Drain-Source Diode Forward Current	$I_S$				9	A
Maximum Pulsed Drain-Source Diode Forward Current	$I_{\text{SM}}$				18	A
Drain-Source Diode Forward Voltage (Note 1)	$V_{\text{SD}}$	$I_S=9.0\text{A}, V_{\text{GS}}=0\text{V}$			1.4	V
Body Diode Reverse Recovery Time (Note 1)	$t_{\text{rr}}$	$I_S=9.0\text{A}, V_{\text{GS}}=0\text{V},$ $dI_F/dt=100\text{A}/\mu\text{s}$		520		nS
Body Diode Reverse Recovery Charge	$Q_{\text{rr}}$			15		$\mu\text{C}$

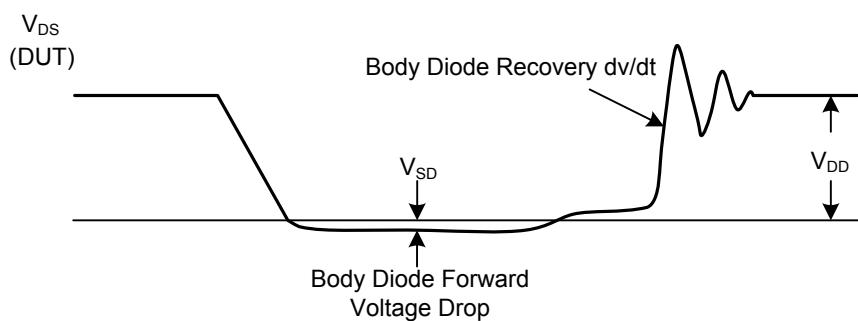
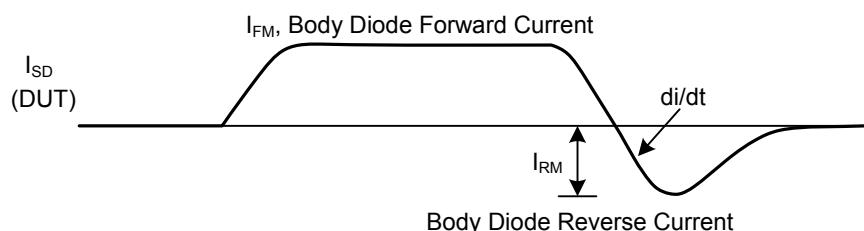
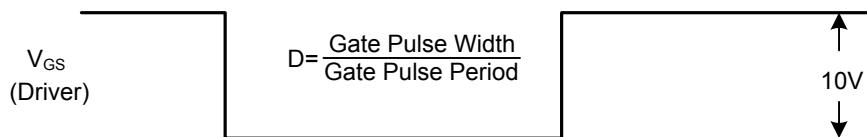
Notes: 1. Pulse Test: Pulse width  $\leq 300\mu\text{s}$ , Duty cycle  $\leq 2\%$ .

2. Essentially independent of operating temperature.

■ TEST CIRCUITS AND WAVEFORMS

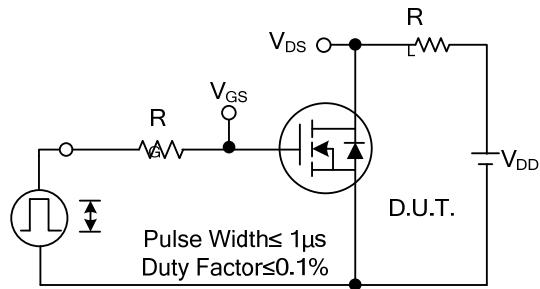


Peak Diode Recovery  $dv/dt$  Test Circuit

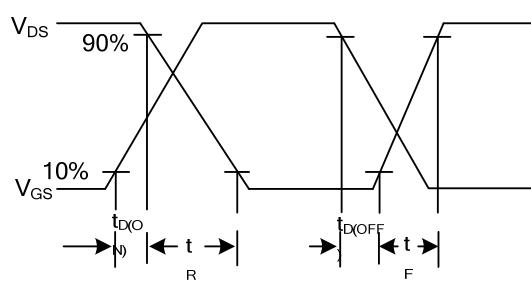


Peak Diode Recovery  $dv/dt$  Waveforms

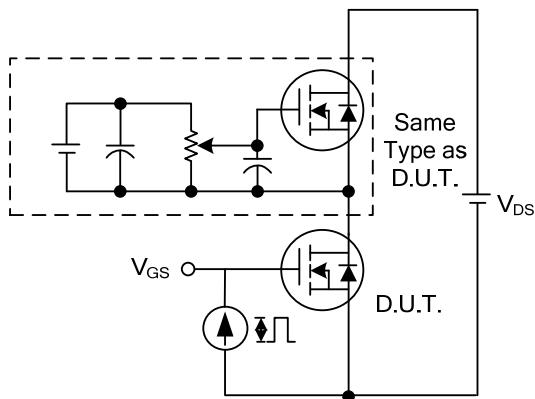
### ■ TEST CIRCUITS AND WAVEFORMS



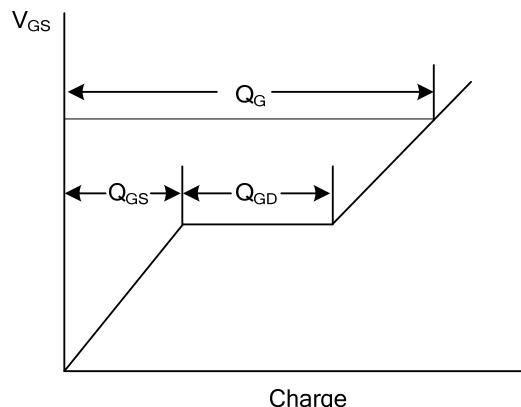
Switching Test Circuit



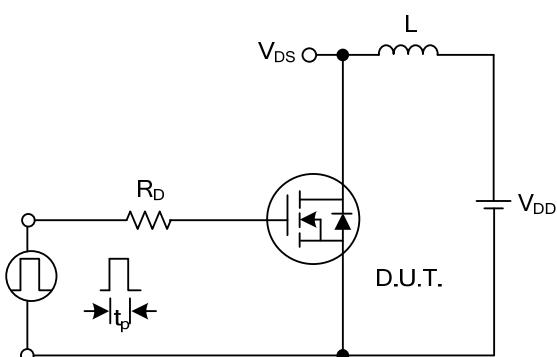
Switching Waveforms



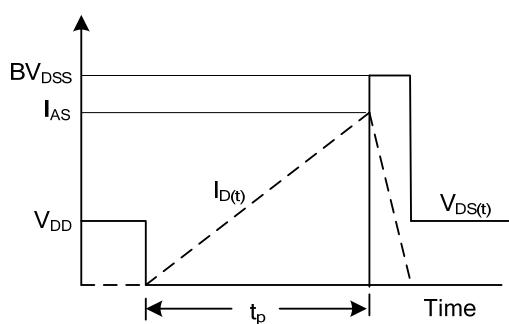
Gate Charge Test Circuit



Gate Charge Waveform

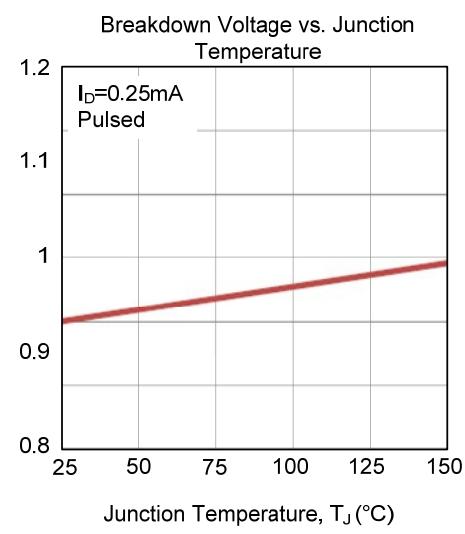
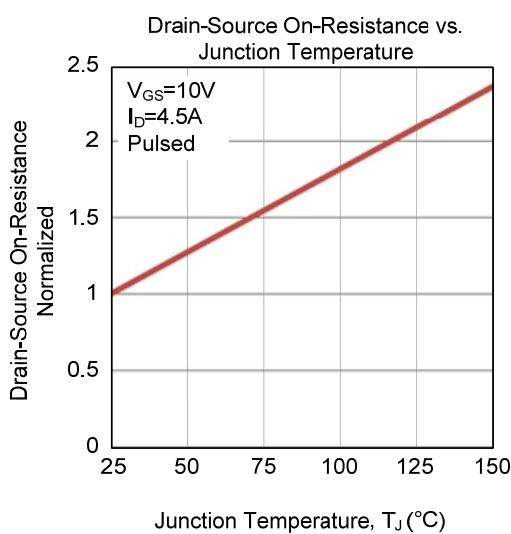
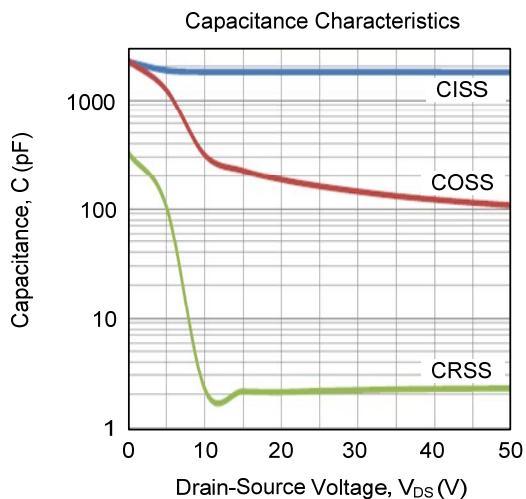
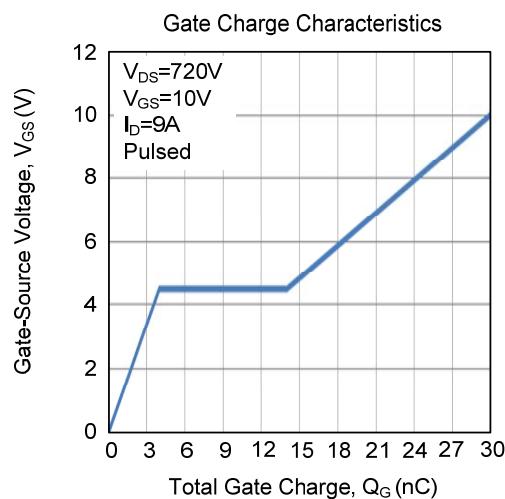
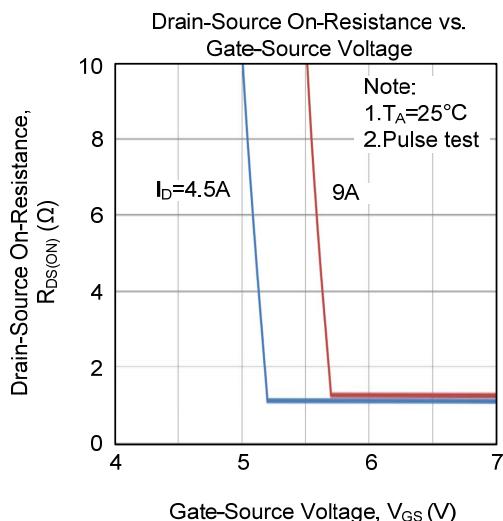
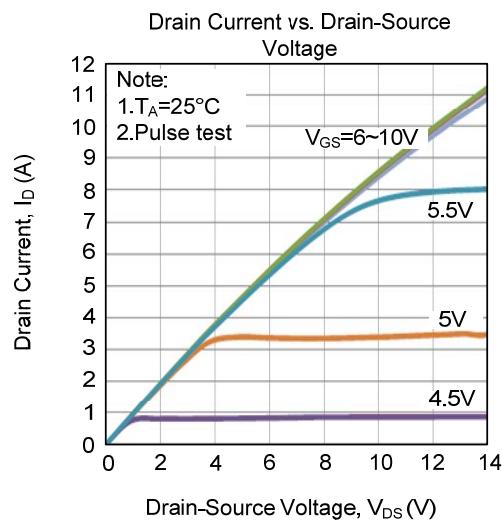


Unclamped Inductive Switching Test Circuit

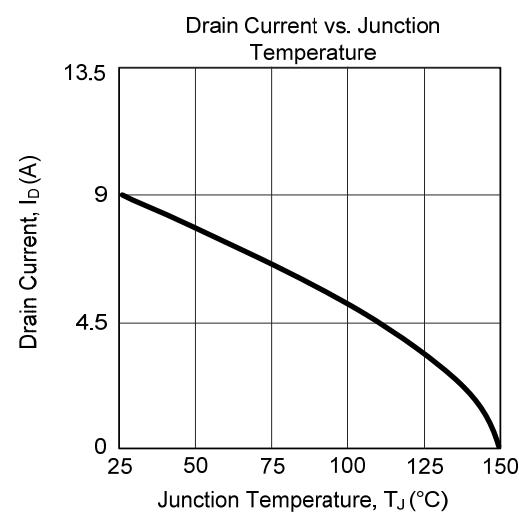
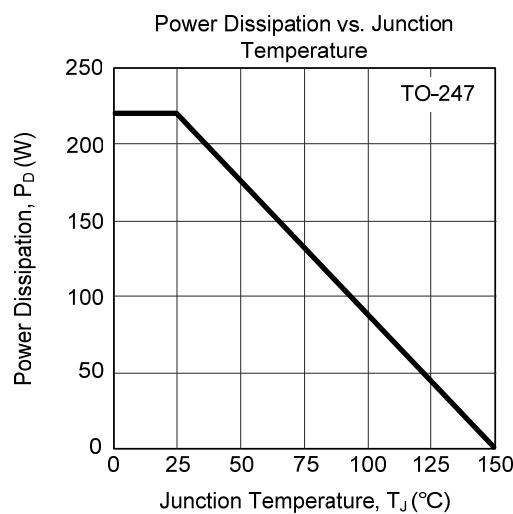
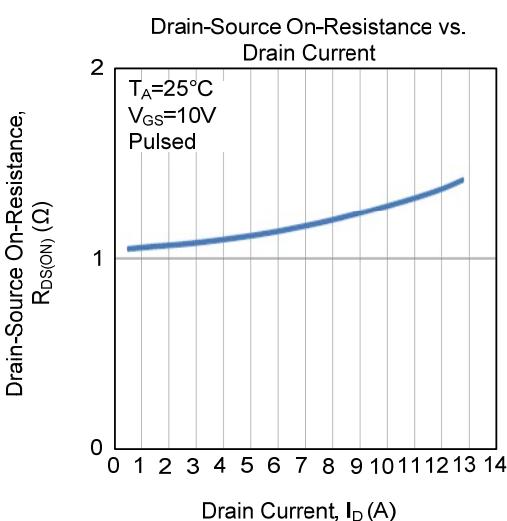
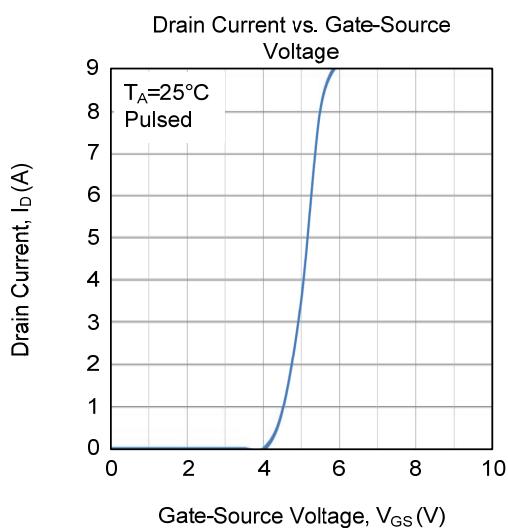
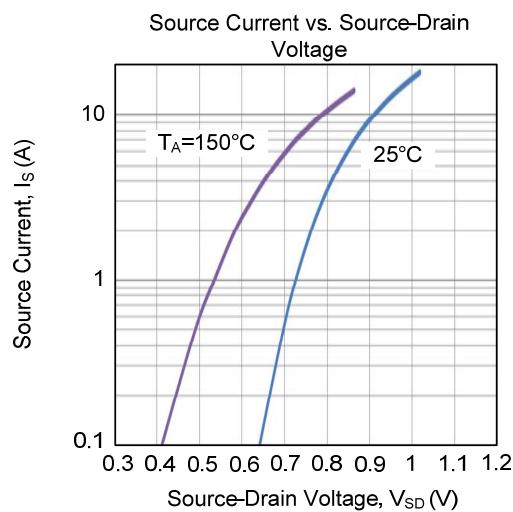
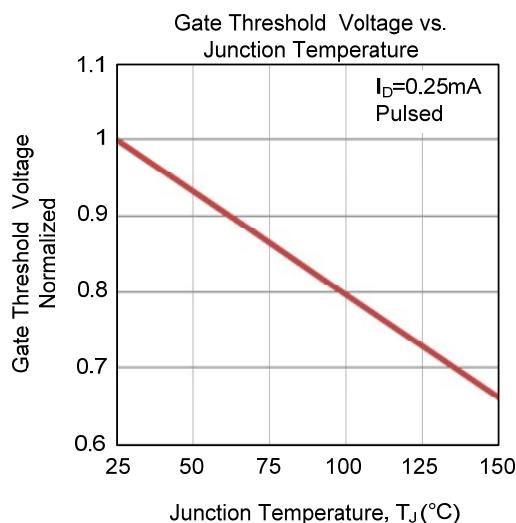


Unclamped Inductive Switching Waveforms

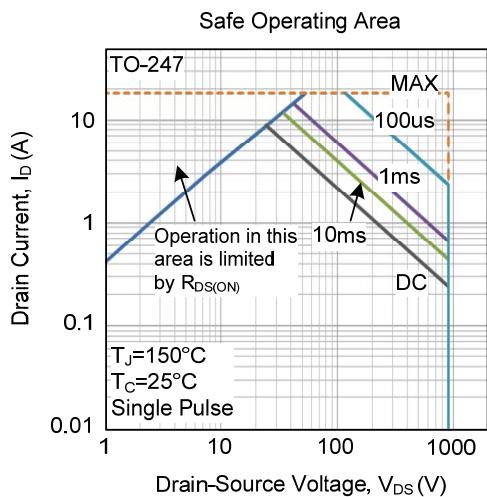
■ TYPICAL CHARACTERISTICS



■ TYPICAL CHARACTERISTICS (Cont.)



- TYPICAL CHARACTERISTICS (Cont.)



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